Transistors

2SB0709A (2SB709A)

Silicon PNP epitaxial planar type

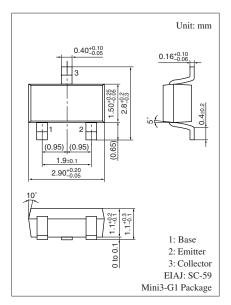
For general amplification Complementary to 2SD0601A (2SD601A)

Features

- \bullet High forward current transfer ratio $h_{F\!E}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit				
Collector-base voltage (Emitter open)	V _{CBO}	-45	V				
Collector-emitter voltage (Base open)	V _{CEO}	-45	V				
Emitter-base voltage (Collector open)	V _{EBO}	-7	V				
Collector current	I _C	-100	mA				
Peak collector current	I _{CP}	-200	mA				
Collector power dissipation	P _C	200	mW				
Junction temperature	Tj	150	°C				
Storage temperature	T _{stg}	-55 to +150	°C				



Marking Symbol: B

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \ \mu A, \ I_{\rm E} = 0$	-45			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-45			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_E = -10 \ \mu A, \ I_C = 0$	-7			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -20 \text{ V}, I_E = 0$			- 0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = -10 \text{ V}, I_B = 0$			-100	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = -10 \text{ V}, I_C = -2 \text{ mA}$	160		460	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{C} = -100 \text{ mA}, I_{B} = -10 \text{ mA}$		- 0.3	- 0.5	V
Transition frequency	f _T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		2.7		pF
(Common base, input open circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

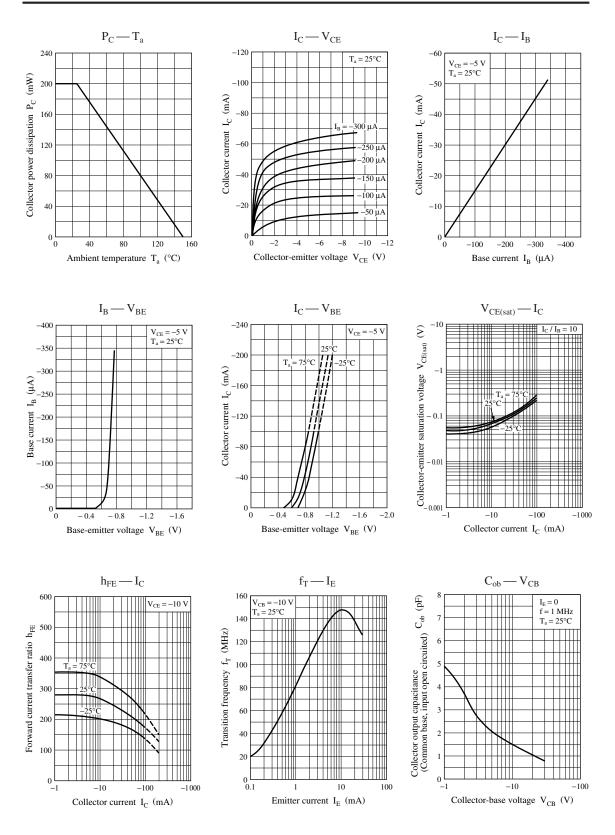
2. *: Rank classification

Rank	Q	R	S	No-rank
h _{FE}	160 to 260	210 to 340	290 to 460	160 to 460
Marking symbol	BQ	BR	BS	В

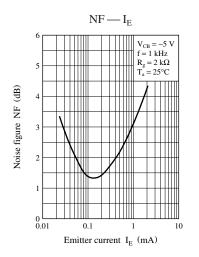
Product of no-rank is not classified and have no marking symbol for rank.

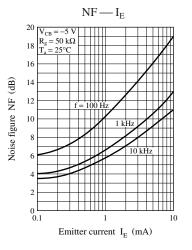
Note) The part number in the parenthesis shows conventional part number.

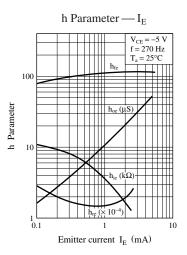
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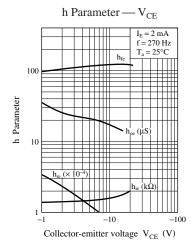


Panasonic









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